

TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

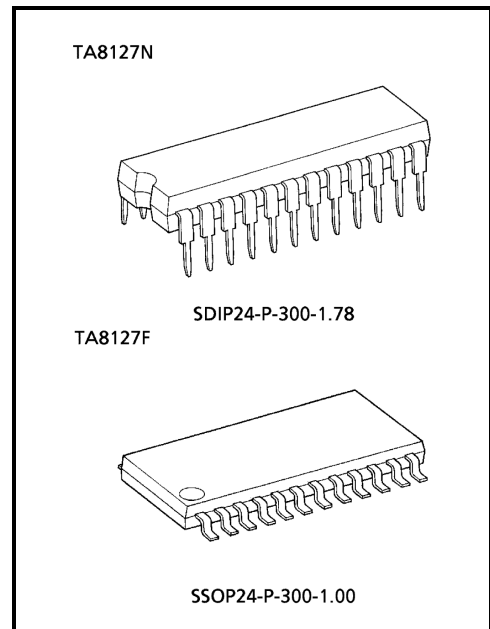
# TA8127N, TA8127F

## 3V AM / FM 1chip Tuner IC

TA8127N and TA8127F are the AM / FM 1chip tuner ICs, which are designed for portable radios and 3V headphone radios.

### Features

- Built-in  
FM F / E, AM / FM IF and FM MPX
- AM detector coil and IF coupling condenser are not needed.
- Compact package  
TA8127N: Shrink DIP 24 pin (1.78mm pitch)  
TA8127F: Mini flat package 24 pin
- Operating supply voltage range  
 $V_{CC} = 1.8 \sim 7.0V$  ( $T_a = 25^\circ C$ )

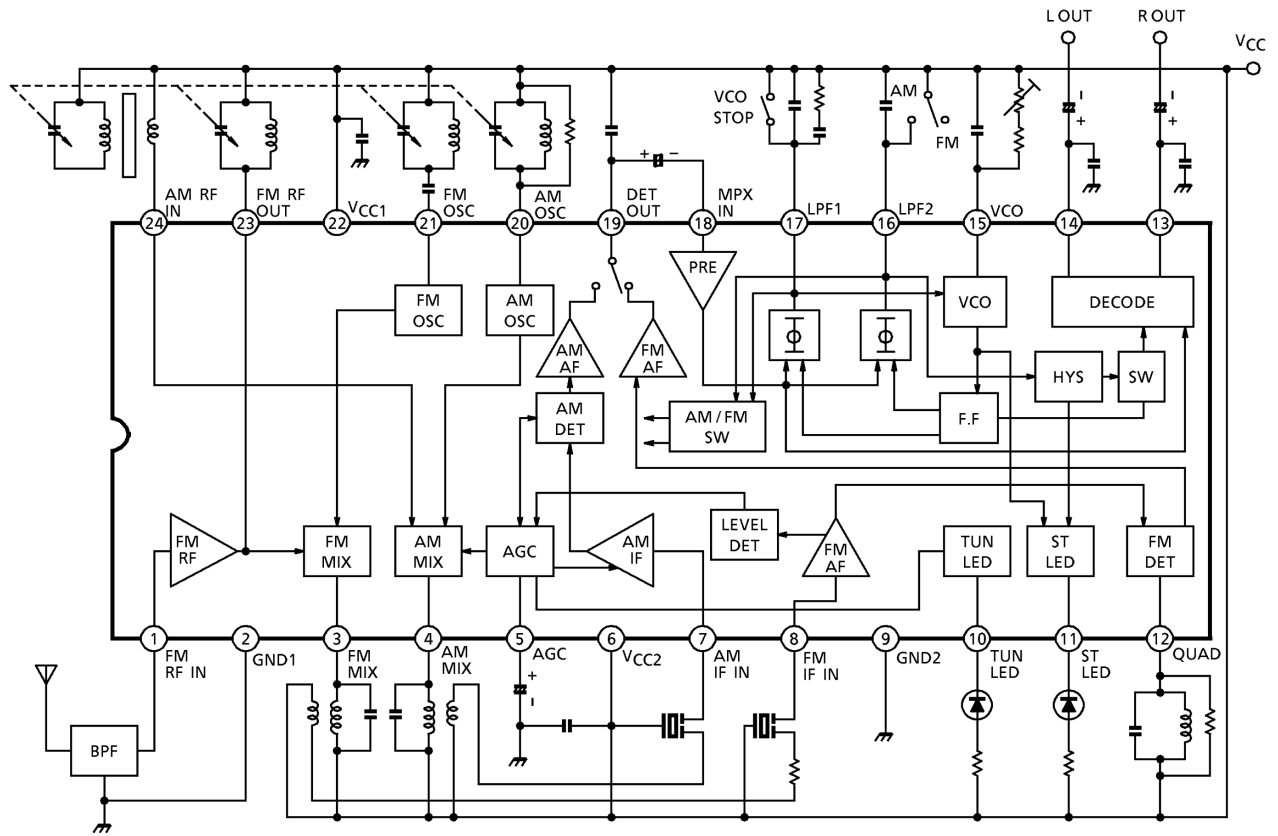


Weight

SDIP24-P-300-1.78: 1.2g (typ.)

SSOP24-P-300-1.00: 0.31 (typ.)

**Block Diagram**



## Explanation Of Terminals

Pin No.	Item	Internal Circuit	DC Voltage (V) (at no Signal)	
			AM	FM
1	FM-RF IN		0	0.7
2	GND1 (GND for RF stage)	—	0	0
3	FM MIX		3.0	3.0
4	AM MIX		3.0	3.0
5	AGC (AM AGC)		0	0
6	VCC2 (VCC for IF / MPX stage)	—	3.0	3.0
7	AM IF IN		3.0	3.0
8	FM IF IN		3.0	3.0

Pin No.	Item	Internal Circuit	DC Voltage (V) (at no Signal)	
			AM	FM
9	GND2 (GND for IF / MPX stage)	—	0	0
10	TUN LED (tuning LED)		—	—
11	ST LED (stereo LED)		—	—
12	QUAD (FM QUAD. Detector)		3.0	3.0
13 14	R-OUT (R-ch output) L-OUT (L-ch output)		1.0	1.0
15	VCO		2.5	2.5 (VCO stop mode)
16	LPF2 <ul style="list-style-type: none"> <li>• LPF terminal for synchronous detector</li> <li>• Bias terminal for AM / FM SW circuit</li> <li><math>V_{16} = V_{CC} \rightarrow</math> AM (VCO stop)</li> <li><math>V_{16} = \text{OPEN} \rightarrow</math> FM</li> </ul>		3.0	2.2 (VCO stop mode 2.7)
17	LPF1 <ul style="list-style-type: none"> <li>• LPF terminal for phase detector</li> <li>• VCO stop terminal</li> <li><math>V_7 = V_{CC} \rightarrow</math> VCO stop</li> </ul>		2.7	2.2

Pin No.	Item	Internal Circuit	DC Voltage (V) (at no Signal)	
			AM	FM
18	MPX IN		0.7	0.7
19	DET OUT	<p>                     (a) LOW→FM, HIGH→AM                      (b) LOW→AM, HIGH→FM                 </p>	1.5	1.2
20	AM OSC		3.0	3.0
21	FM OSC		3.0	3.0
22	V <sub>CC1</sub> (V <sub>CC</sub> for RF stage)	—	3.0	3.0
23	FM RF OUT	Cf. Pin(1)	3.0	3.0
24	AM RF IN		3.0	3.0

## Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Supply voltage		V <sub>CC</sub>	8	V
LED current		I <sub>LED</sub>	10	mA
LED voltage		V <sub>LED</sub>	8	V
Power dissipation	TA8127N	P <sub>D</sub> (Note)	1200	mW
	TA8127F		400	
Operating temperature		T <sub>opr</sub>	-25~75	°C
Storage temperature		T <sub>stg</sub>	-55~150	°C

Note: Derated above 25°C in the proportion of 9.6mW / °C for TA8127N and of 3.2mW / °C for TA8127F.

## Electrical Characteristics

Unless Otherwise Specified,

Ta = 25°C, V<sub>CC</sub> = 3V, F / E: f = 83MHz, f<sub>m</sub> = 1kHz

FM IF: f = 10.7MHz, Δf = ±22.5kHz, f<sub>m</sub> = 1kHz

AM: f = 1MHz, MOD = 30%, f<sub>m</sub> = 1kHz

MPX: f<sub>m</sub> = 1kHz

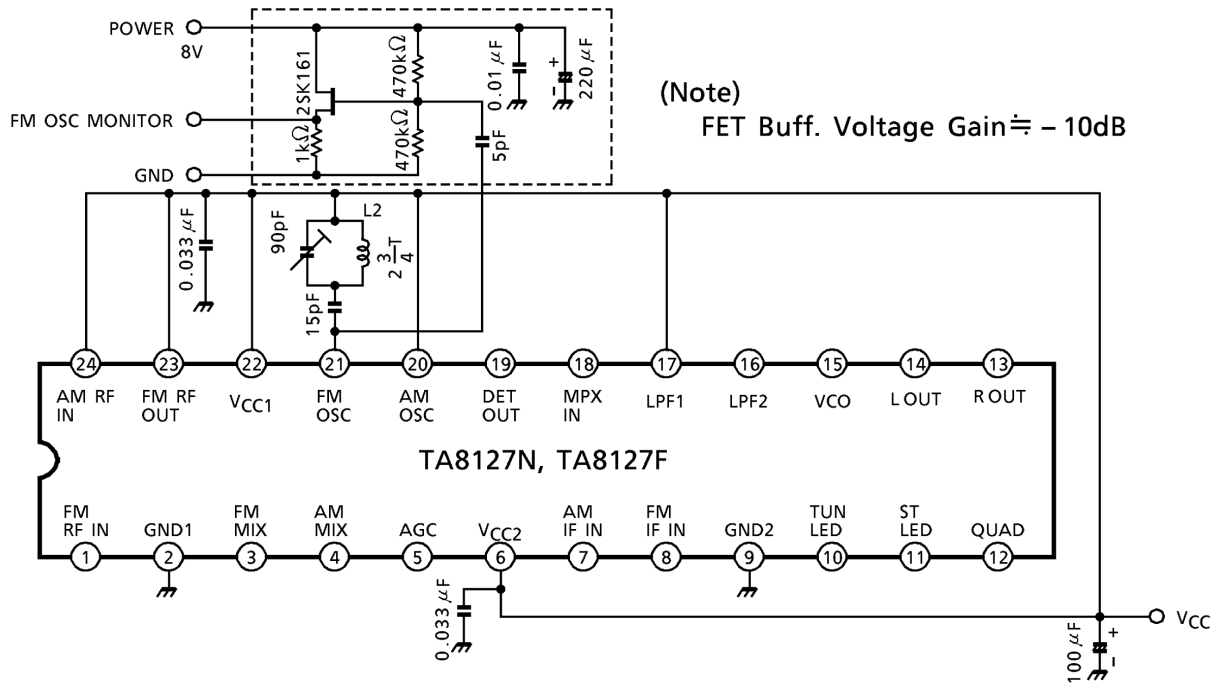
Characteristic		Symbol	Test Circuit	Test Condition	Min.	Typ.	Max.	Unit
Supply current		I <sub>CC</sub> (FM)	1	V <sub>in</sub> = 0, FM mode	—	13.2	20.0	mA
		I <sub>CC</sub> (AM)	1	V <sub>in</sub> = 0, AM mode	—	8.4	13.5	
F / E	Input limiting voltage	V <sub>in</sub> (lim.)	1	- 3dB limiting	—	10.0	—	dBμV EMF
	Local OSC voltage	V <sub>OSC</sub>	2	f <sub>OSC</sub> = 72.3MHz	—	105	—	mV <sub>rms</sub>
FM IF	Input limiting voltage	V <sub>in</sub> (lim.) <sub>IF</sub>	1	- 3dB limiting	40	46	53	dBμV EMF
	Recovered output voltage	V <sub>OD</sub>	1	V <sub>in</sub> = 80dBμV EMF	55	80	110	mV <sub>rms</sub>
	Signal to noise ratio	S / N	1	V <sub>in</sub> = 80dBμV EMF	—	70	—	dB
	Total harmonic distortion	THD	1	V <sub>in</sub> = 80dBμV EMF	—	0.4	—	%
	AM rejection ratio	AMR	1	V <sub>in</sub> = 80dBμV EMF	—	32	—	dB
	Lamp on sensitivity	V <sub>L</sub>	1	I <sub>L</sub> = 1mA	45	51	56	dBμV EMF
AM	Gain	G <sub>V</sub>	1	V <sub>in</sub> = 26dBμV EMF	40	70	110	mV <sub>rms</sub>
	Recovered output voltage	V <sub>OD</sub>	1	V <sub>in</sub> = 60dBμV EMF	55	80	110	
	Signal to noise ratio	S / N	1	V <sub>in</sub> = 60dBμV EMF	—	42	—	dB
	Total harmonic distortion	THD	1	V <sub>in</sub> = 60dBμV EMF	—	1.0	—	%
	Lamp on sensitivity	V <sub>L</sub>	1	I <sub>L</sub> = 1mA	20	25	30	dBμV EMF
Pin(19) output resistance		R <sub>19</sub>	1	FM mode	—	0.75	—	kΩ
				AM mode	—	12.5	—	

Characteristic		Symbol	Test Circuit	Test Condition	Min.	Typ.	Max.	Unit		
MPX	Input resistance	$R_{IN}$	—	—	—	24	—	k $\Omega$		
	Output resistance	$R_{OUT}$	—	—	—	5	—			
	Max. Composite signal input voltage		$V_{in (max.)}$ stereo	1	L+R = 90%, P = 10% $f_m = 1\text{kHz}$ , THD = 3%	—	350	—	mV <sub>rms</sub>	
	Separation		Sep	1	L+R = 135mV <sub>rms</sub> P = 15mV <sub>rms</sub>	$f_m = 100\text{Hz}$	—	42	—	dB
						$f_m = 1\text{kHz}$	35	42	—	
						$f_m = 10\text{kHz}$	—	42	—	
	Total harmonic distortion	Monaural	THD (monaural)	1	$V_{in} = 150\text{mV}_{rms}$		—	0.2	—	%
		Stereo	THD (stereo)		L+R = 135mV <sub>rms</sub> , P = 15mV <sub>rms</sub>		—	0.2	—	
	Voltage gain		$G_V (MPX)$	1	$V_{in} = 150\text{mV}_{rms}$		-5	-3	-1	dB
	Channel balance		C. B.	1	$V_{in} = 150\text{mV}_{rms}$		-2	0	2	
	Stereo lamp sensitivity	On	$V_L (ON)$	1	Pilot input		—	8	16	mV <sub>rms</sub>
		Off	$V_L (OFF)$		Pilot input		2	6	—	
Stereo lamp hysteresis		$V_H$	1	To LED turn off from LED turn on		—	2	—	mV <sub>rms</sub>	
Caputure range		C. R.	1	P = 15mV <sub>rms</sub>		—	±3	—	%	
Signal to noise ratio		S / N	1	$V_{in} = 150\text{mV}_{rms}$		—	70	—	dB	





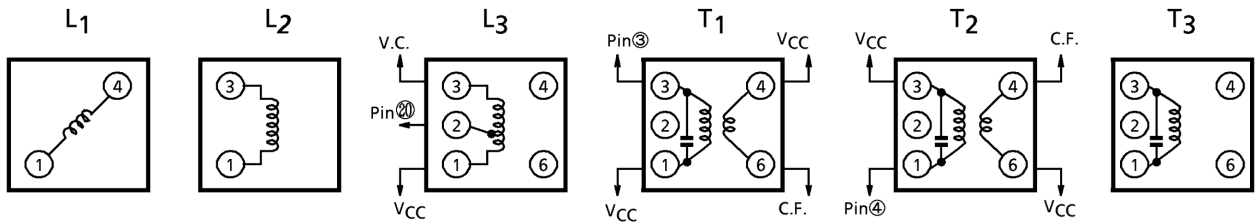
## Test Circuit 2



## Coil Data

Coil No.	Test Freq. (Hz)	L (μH)	C <sub>O</sub> (pF)	Q <sub>O</sub>	Turns					Wire (mmφ)	Reference
					1-2	2-3	1-3	1-4	4-6		
L <sub>1</sub> FM RF	100M	—	—	100	—	—	—	2 1/2	—	0.5UEW	(S) 53T-037-202
L <sub>2</sub> FM OSC	100M	—	—	100	—	—	2 3/4	—	—	0.5UEW	(S) 0258-244
L <sub>3</sub> AM OSC	796k	288	—	115	13	73	—	—	—	0.08UEW	(S) 4147-1356-038
T <sub>1</sub> FM MIX	10.7M	—	75	100	—	—	13	—	2	0.1UEW	(S) 2153-414-041
T <sub>2</sub> AM MIX	455k	—	180	120	—	—	180	—	15	0.08UEW	(S) 2150-2162-165
T <sub>3</sub> FM DET	10.7M	—	47	165	—	—	16	—	—	0.09UEW	(S) 2153-4095-122

(S): SUMIDA electric CO., LTD



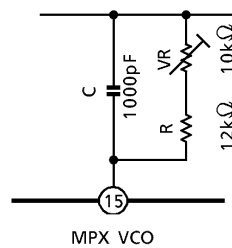
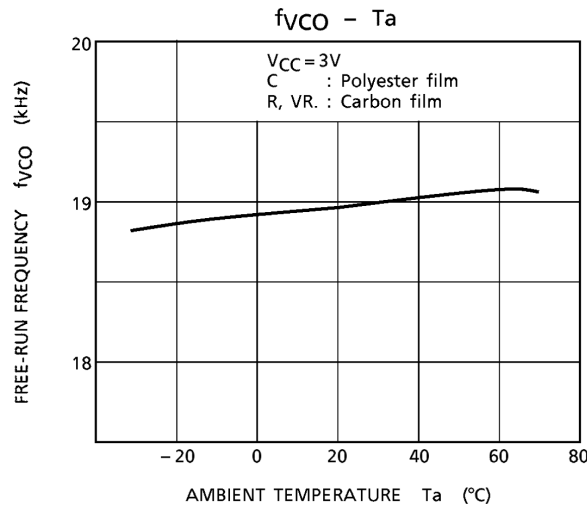
## Hint On Use Of TA8127N And TA8127F

External parts of MPX VCO

- (1) Temperature characteristic of MPX VCO free-run frequency. The temperature characteristic of MPX VCO is shown in the diagram as below. Select one with a better temperature characteristic (C, R and VR. ) in use. We recommend,

C : Polyester film

R, VR: Carbon film



- (2) Value of the external parts

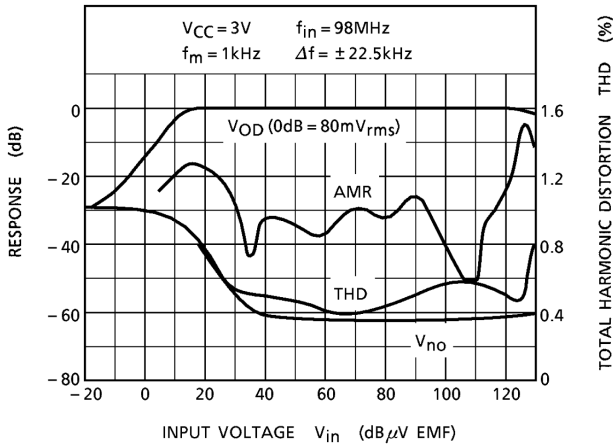
We recommend to set up these value as below.

R = 12kΩ

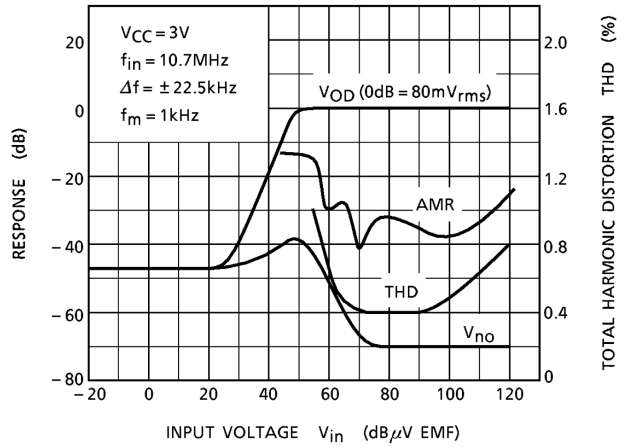
VR = 10kΩ

C = 1000pF

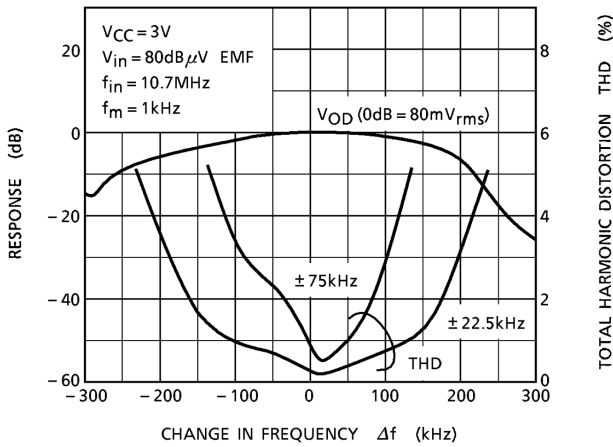
FM (F/E + IF)  
V<sub>OD</sub>, V<sub>no</sub>, THD, AMR - V<sub>in</sub>



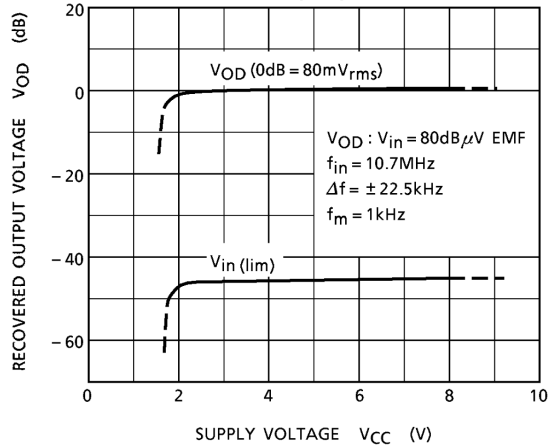
FM (IF)  
V<sub>OD</sub>, V<sub>no</sub>, THD, AMR - V<sub>in</sub>



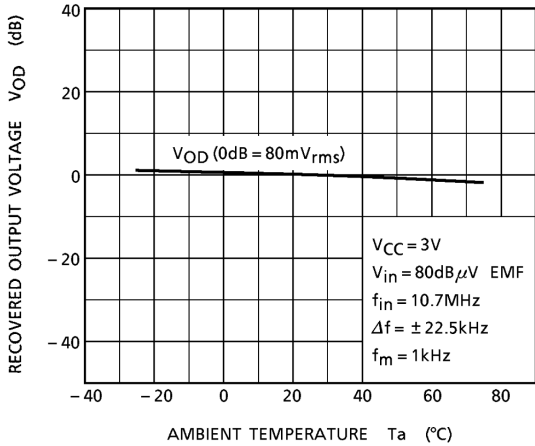
FM (IF)  
V<sub>OD</sub>, THD -  $\Delta f$



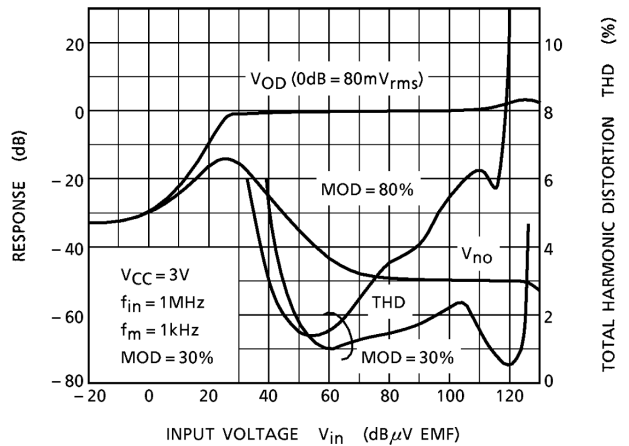
FM (IF)  
V<sub>OD</sub>, V<sub>in</sub> (lim.) - V<sub>CC</sub>

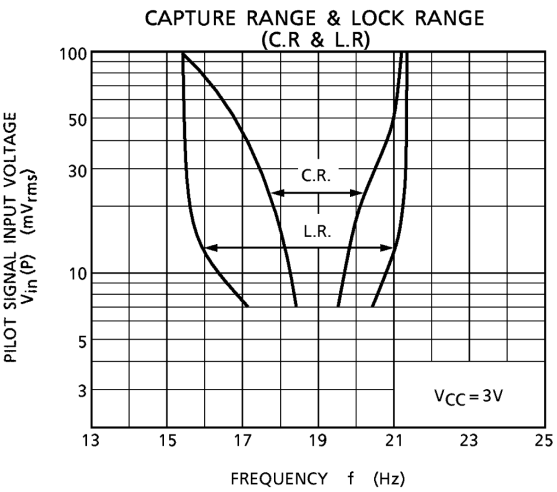
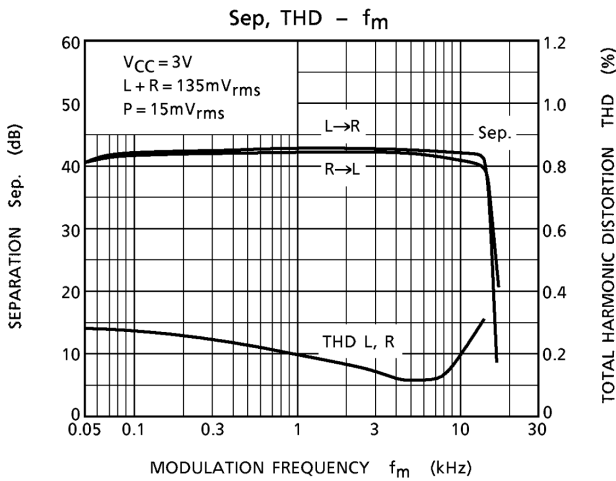
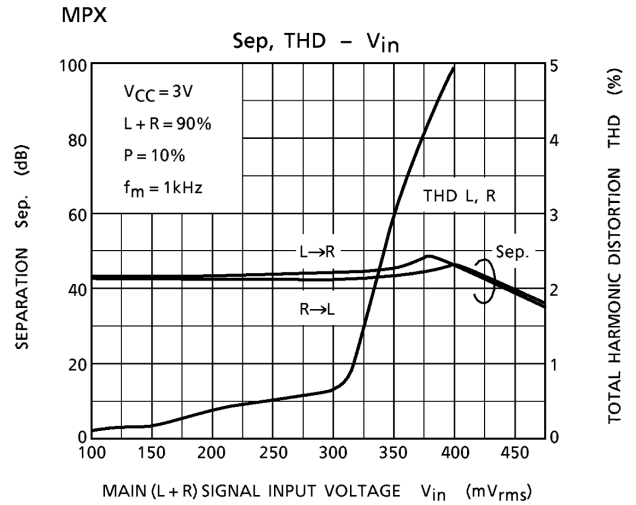
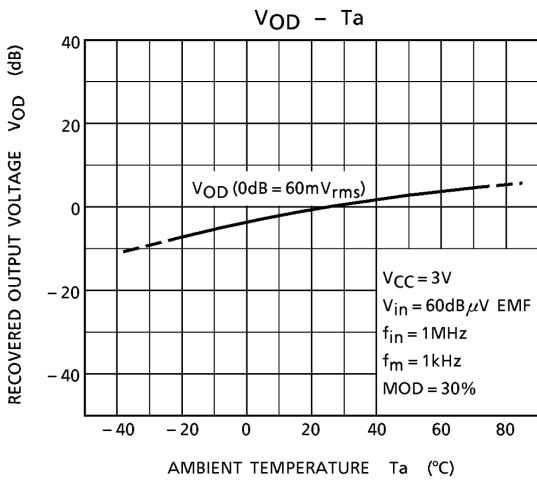
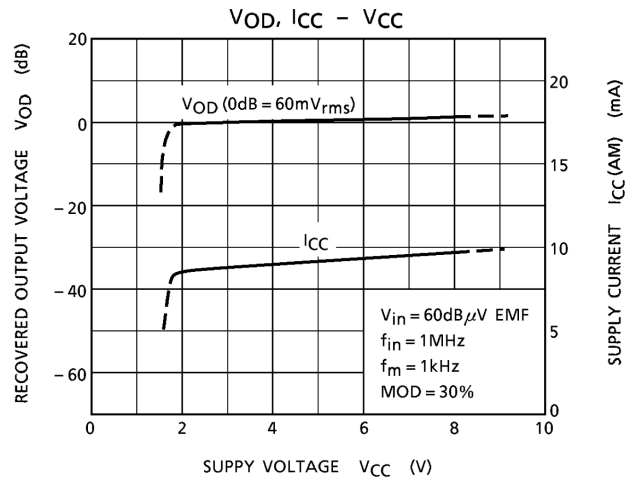
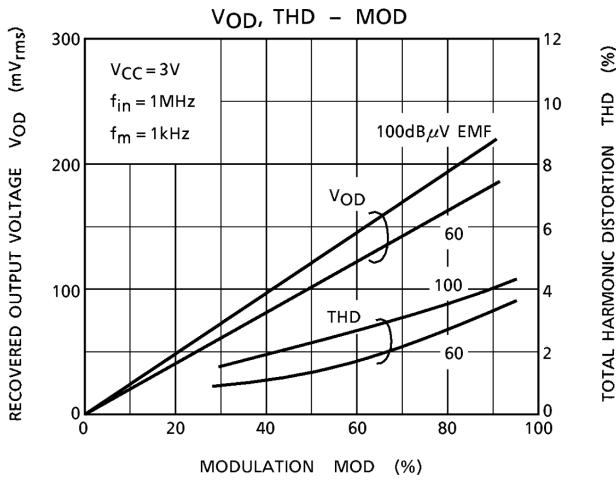


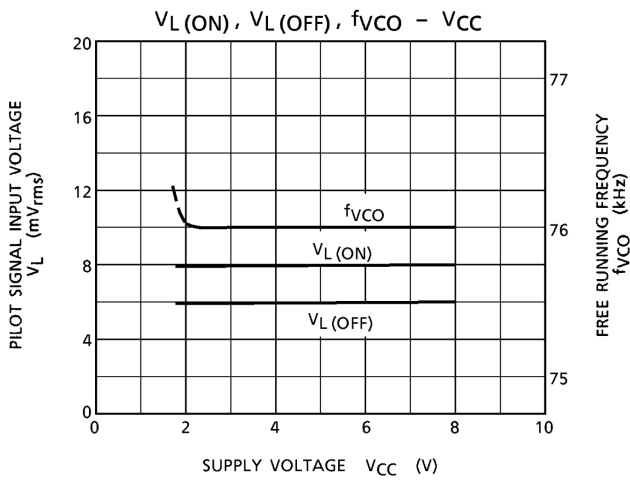
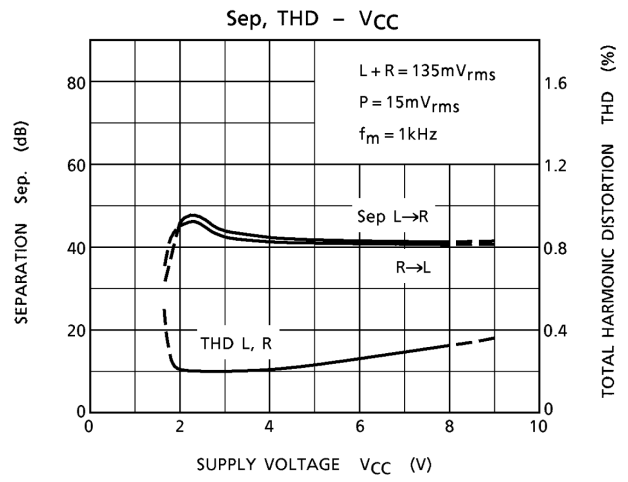
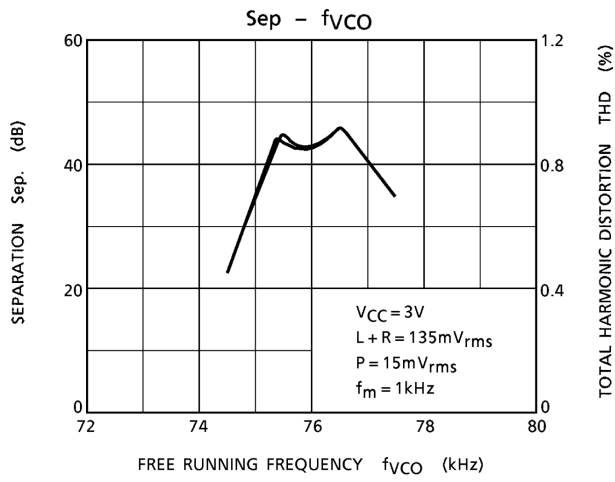
FM (IF)  
V<sub>OD</sub> - T<sub>a</sub>



AM  
V<sub>OD</sub>, V<sub>no</sub>, THD - V<sub>in</sub>



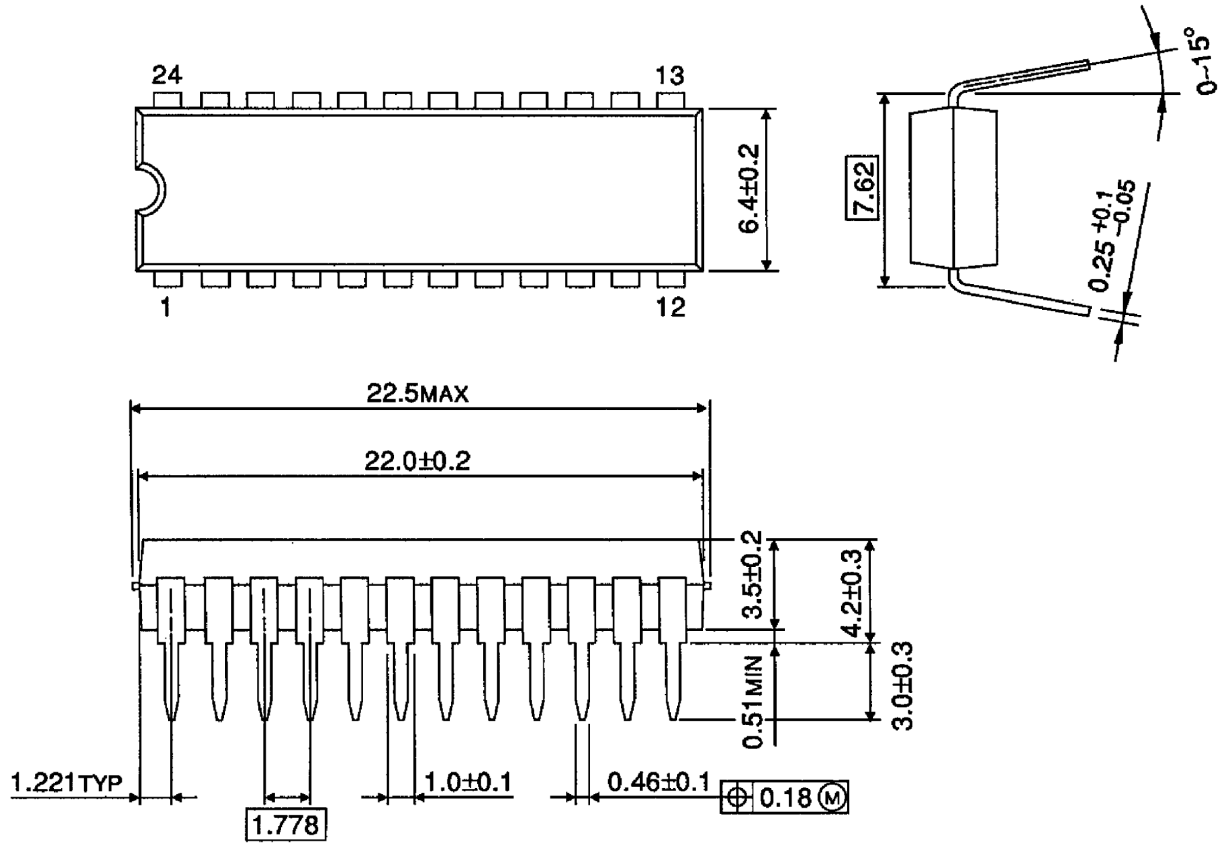




## Package Dimensions

SDIP24-P-300-1.78

Unit : mm

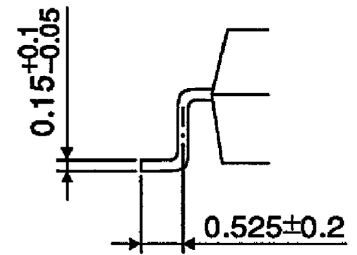
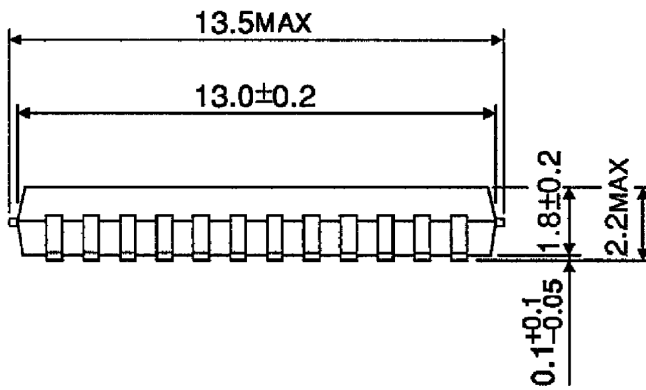
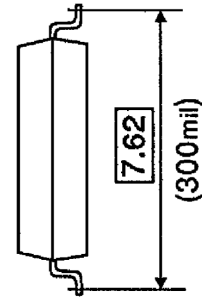
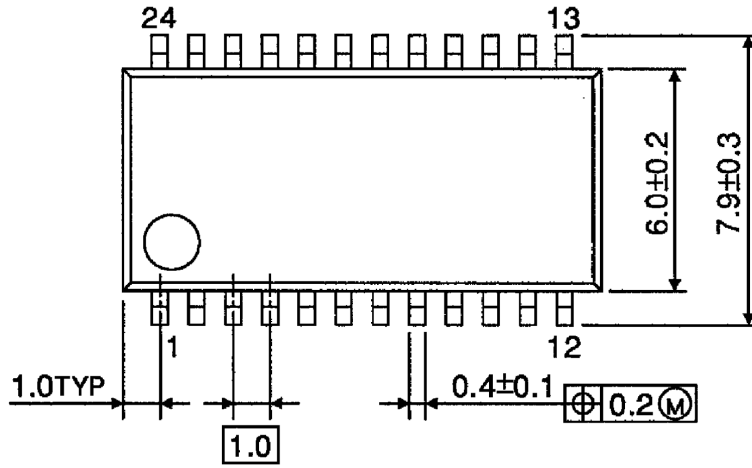


Weight: 1.2g (typ.)

**Package Dimensions**

SSOP24-P-300-1.00

Unit : mm



Weight: 0.31g (typ.)



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000707EBA

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